

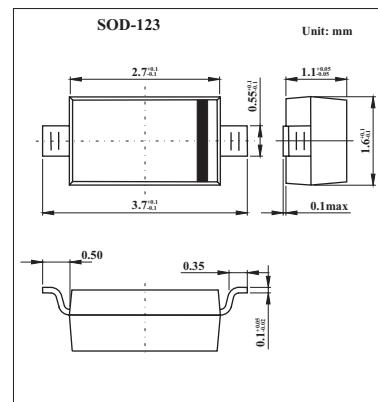


## SURFACE MOUNT FAST SWITCHING DIODE

## 1N4148W

## ■ Features

- Fast Switching Speed
- Surface Mount Package Ideally Suited for Automatic Insertion
- For General Purpose Switching Applications
- High Conductance



## ■ Absolute Maximum Ratings Ta = 25°C

Parameter	Symbol	Rating	Unit
Non-repetitive peak reverse voltage	V <sub>RM</sub>	100	V
Peak repetitive reverse voltage	V <sub>RRM</sub>		
Working peak reverse voltage	V <sub>RWM</sub>	75	V
DC blocking voltage	V <sub>R</sub>		
RMS reverse voltage	V <sub>R(RMS)</sub>	53	V
Average rectified output current	I <sub>O</sub>	150	mA
Forward continuous current	I <sub>FM</sub>	300	mA
Non-repetitive peak forward surge current@ t = 1.0s @ t = 1.0 us	I <sub>FSM</sub>	1.0 2.0	A
Power dissipation	P <sub>D</sub>	400	mW
Typical thermal resistance, junction to ambient air	R <sub>θJA</sub>	315	°C/W
Junction temperature	T <sub>J</sub>	125	°C
Storage temperature	T <sub>STG</sub>	-65 to 150	°C

## ■ Electrical Characteristics Ta = 25°C

Parameter	Symbol	Testconditons	Min	Typ	Max	Unit
Forward voltage	V <sub>F1</sub>	I <sub>F</sub> = 1mA			0.715	V
	V <sub>F2</sub>	I <sub>F</sub> = 10mA			0.855	
	V <sub>F3</sub>	I <sub>F</sub> = 50mA			1.0	
	V <sub>F4</sub>	I <sub>F</sub> = 150mA			1.25	
Peak reverse current	I <sub>R1</sub>	V <sub>R</sub> = 75V			1	μ A
	I <sub>R2</sub>	V <sub>R</sub> = 20V			25	μ A
Capacitance	C <sub>J</sub>	V <sub>R</sub> = 0, f = 1.0MHz			2	pF
Reverse recovery time	t <sub>rr</sub>	I <sub>F</sub> =I <sub>R</sub> =10mA, I <sub>rr</sub> =0.1X I <sub>R</sub> , R <sub>L</sub> =100Ω			4	ns

## ■ Marking

Marking	T4
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■ Typical Characteristic

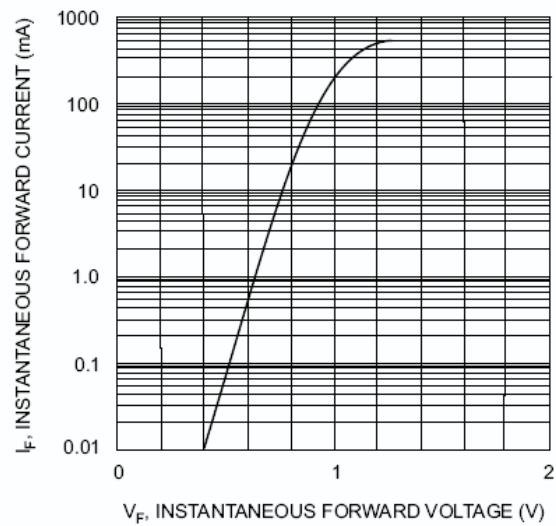


Fig. 1 Forward Characteristics

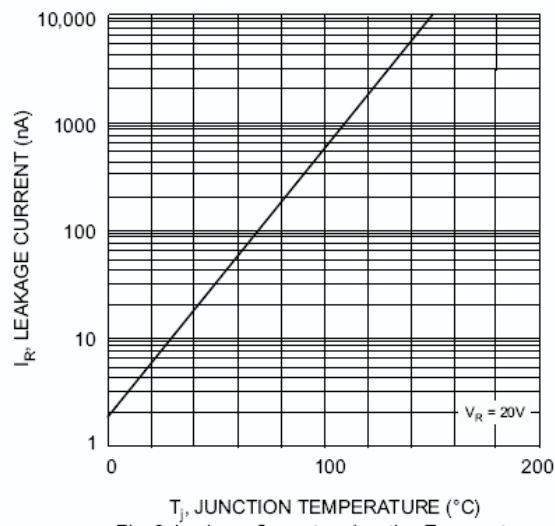


Fig. 2 Leakage Current vs Junction Temperature